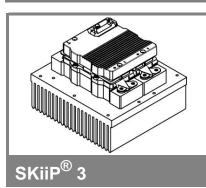
SKiiP 1013GB172-2DL



2-pack-integrated intelligent Power System

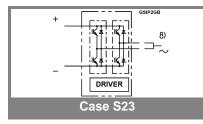
Power Section

SKiiP 1013GB172-2DL

Data

Power section features

- SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP[®] 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- 1) with assembly of suitable MKP capacitor per terminal
- 8) AC connection busbars must be connected by the user; copper busbars available on request



Absolute	Maximum Ratings	s = 25 °C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
V _{CES}		1700	V			
V _{CES} V _{CC} ¹⁾	Operating DC link voltage	1200	V			
V _{GES}		± 20	V			
I _C	T _s = 25 (70) °C	1000 (750)	А			
Inverse diode						
I _F = - I _C	T _s = 25 (70) °C	830 (630)	А			
I _{FSM}	T _j = 150 °C, t _p = 10 ms; sin	6900	А			
I²t (Diode)	Diode, T _j = 150 °C, 10 ms	238	kA²s			
T _j , (T _{stg})		- 40 + 150 (125)	°C			
V _{isol}	rms, AC, 1 min, main terminals to heat sink	4000	V			
I _{AC-terminal}	per AC terminal, rms, T _s = 70 °C,	400	А			
	$T_{terminal} \leq 115 \ ^{\circ}C$					

Characteristics T _s = 25 °C unless otherwise spec						specified		
Symbol	Conditions			min.	typ.	max.	Units	
IGBT								
V _{CEsat}	I _C = 600 A measured at t	, T _j = 25 (1 ^{erminal}	25) °C;			1,9 (2,2)	2,4	V
V _{CEO}	T _j = 25 (12					1 (0,9)	1,2 (1,1)	V
r _{CE}	T _j = 25 (12	25) °C; at te	erminal			1,5 (2,1)	1,9 (2,5)	mΩ
I _{CES}	$V_{GE} = 0 V,$	$V_{CE} = V_{CI}$	ES'			2,4 (144)		mA
E _{on} + E _{off}	T _j = 25 (125) °C I _C = 600 A, V _{CC} = 900 V				390		mJ	
-on -oπ	$T_i = 125 °C$					575		mJ
R _{CC+EE}	,					0,25		mΩ
L _{CE}	terminal chip, T _j = 25 °C top, bottom				6		nH	
C _{CHC}	per phase	AC-side				3,4		nF
Inverse o	diode				1			l
V _F = V _{EC}	I _F = 600 A measured at t	, T _j = 25 (1 ^{erminal}	25) °C			2 (1,8)	2,15	V
V _{TO}	T _i = 25 (12	25) °C				1,1 (0,8)	1,2 (0,9)	V
r _T	T _i = 25 (12	25) °C				1,5 (1,7)	1,6 (1,8)	mΩ
E _{rr}	I _C = 600 A					72		mJ
	T _j = 125 °C	C, V _{CC} = 12	200 V			86		mJ
Mechani	cal data							
M _{dc}	DC termin				6		8	Nm
M_{ac}	AC terminals, SI Units			13		15	Nm	
W	SKiiP [®] 3 System w/o heat sink				1,7		kg	
w	heat sink					5,4		kg
	e to heat					SKF 16B		
R _{th(i-s)I}	per IGBT						0,03	K/W
R _{th(j-s)D}	per diode						0,058	K/W
Z _{th}	R _i (mK/W) (max. values)			tau _i (s)				
	1	2	3	4	1	2	3	4
Z _{th(j-r)I}	9,8	16,4	3,8	0	0,37	0,06	0,01	1
Z _{th(j-r)D}	10	24	24	36	50	5	0,25	0,04
Z _{th(r-a)}	4,3	20,3	7,1	2,3	160	53	9	0,4

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of

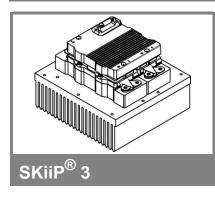
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SKiiP 1013GB172-2DL



2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 1013GB172-2DL

Data

Gate driver features

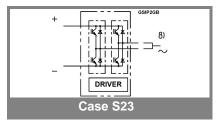
- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protection against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute	Maximum Ratings	$T_a = 25 \degree C$ unless otherwise specified		
Symbol	Conditions	Values	Units	
V _{S2}	unstabilized 24 V power supply	30	V	
V _i	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/µs	
V _{isollO}	input / output (AC, rms,)	4000	V	
V _{isolPD}	partial discharge extinction voltage, rms, Q _{PD} pC;	1500	V	
V _{isol12}	output 1 / output 2 (AC, rms,)	1500	V	
f	switching frequency	14	kHz	
f _{out}	output frequency for $I_{peak(1)} = I_C$	14	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 + 85	°C	

Characte	eristics T _a	a = 25 °C unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
V _{S2}	supply voltage non stabilized	13	24	30	V
I _{S2}	V _{S2} = 24 V	320+23*f/kHz+0,00022*(I _{AC} /A) ²			mA
V _{iT+}	input threshold voltage (High)			12,3	V
V _{iT-}	input threshold voltage (Low)	4,6			V
R _{IN}	input resistance		10		kΩ
C _{IN}	input capacitance		1		nF
t _{d(on)IO}	input-output turn-on propagation time		1,3		μs
t _{d(off)IO}	input-output turn-off propagation time		1,3		μs
t _{pERRRESET}	error memory reset time	9			μs
t _{TD}	top / bottom switch interlock time		3,3		μs
I _{analogOUT}	max. 5mA; 8 V corresponds to 15 V supply voltage for external components		1000		A
I _{s1out}	max. load current			50	mA
I _{TRIPSC} T _{tp}	over current trip level (I _{analog} OUT = 10 V) over temperature protection U _{DC} -protection (U _{analog OUT} = 9 V);	110	1250 not	120	A °C V
U _{DCTRIP}	O_{DC} -protection ($O_{analog OUT} = 9$ V), (option for GB types)	i	mplemente	d	v

For electrical and thermal design support please use SEMISEL. Access to SEMISEL is via SEMIKRON website http://www.semikron.com.

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